

MULTI-INNO TECHNOLOGY CO., LTD.

www.multi-inno.com

OLED MODULE SPECIFICATION

Model: MI12864LO-W

This module uses ROHS material

For Customer's Acceptance:

Customer		
Approved		
Comment		

This specification may change without prior notice in
order to improve performance or quality. Please contact
Multi-Inno for updated specification and product status
before design for this product or release of this order.

Revision	1.2
Engineering	
Date	2016-03-08
Our Reference	



REVISION RECORD

REV NO.	REV DATE	CONTENTS	REMARKS
1.0	2013-04-03	Preliminary	
1.1	2013-06-25	Change Polarizer Size Change R IREF=390K to R IREF=910K Update Actual Application Example	
1.2	2016-03-08	Modify supply voltage for display (supplied externally) from 11.5V(Min.),12V(Typ.) and 12.5V(Max.) to 8.5V(Min.),9V(Typ.) and 9.5V(Max.)	P.7
		1.Modify brightness(Vcc supplied externally) from 150cd/m^2(min) to 120cd/m^2(min). 2.Modify Brightness(Vcc generated by internal DC/DC) from 150cd/m^2(min) and 180cd/m^2(typ) to 80cd/m^2(min) and 120cd/m^2(typ). 3.Modify color coordinate:	P.26
		The principle diagram of the application of add special tips.	P.9,11,13,15,17

CONTENT

- PHYSICAL DATA
- EXTERNAL DIMENSIONS
- ABSOLUTE MAXIMUM RATINGS
- ELECTRICAL CHARACTERISTICS
- TIMING OF POWER SUPPLY
- ELECTRO-OPTICAL CHARACTERISTICS
- INTERFACE PIN CONNECTIONS
- RELIABILITY TESTS
- OUTGOING QUALITY CONTROL SPECIFICATION
- CAUTIONS IN USING OLED MODULE

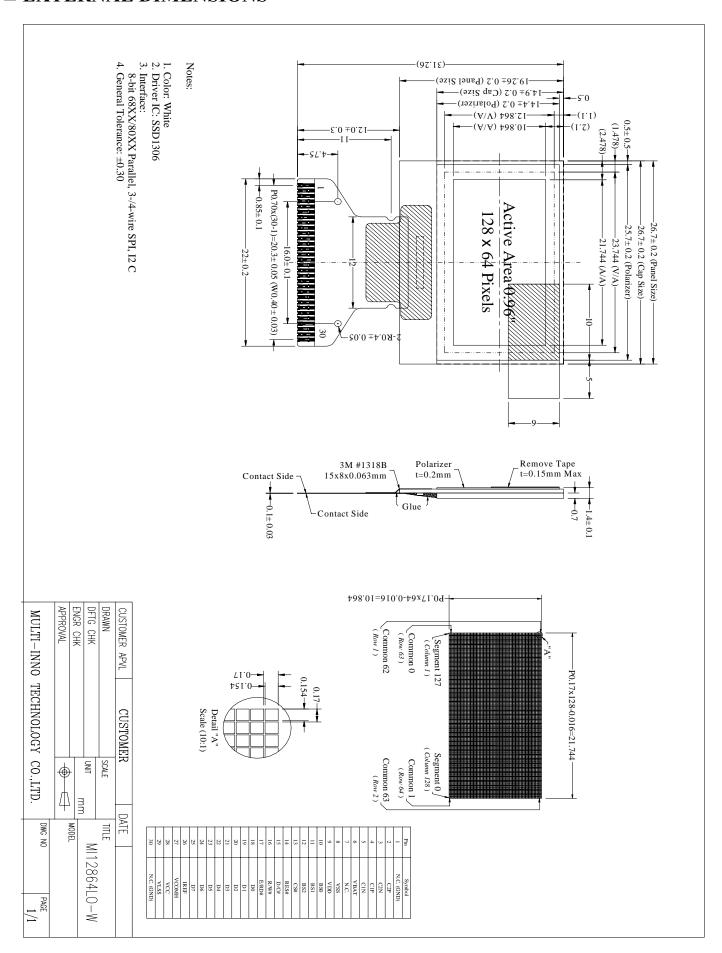


■ PHYSICAL DATA

No.	Items	Specification	Unit
1	Display Mode	Passive Matrix OLED	-
2	Display Color	Monochrome (White)	-
3	Duty	1/64	-
4	Resolution	128(H) x 64 (V)	Pixel
5	Active Area	21.744 (W) x 10.864 (H)	mm
6	Outline Dimension	26.70 (W) x 19.26 (H) x 1.4 (D)	mm
7	Pixel Pitch	0.17 (W) x 0.17 (H)	mm
8	Pixel Size	0.154 (W) x 0.154 (H)	mm
9	Driver IC	SSD1306	-
10	Interface	8-bit parallel,3-/4-wire SPI,I2C	-
11	Weight	1.54	g



■ EXTERNAL DIMENSIONS





■ ABSOLUTE MAXIMUM RATINGS

Items	Symbol	Min	Тур.	Max	Unit	Notes
Supply voltage for logic	V_{DD}	-0.3	-	4	V	1,2
Supply voltage for display	V_{CC}	0	-	16.0	V	1,2
Supply voltage for DC/DC	V_{BAT}	-0.3	-	5.0	V	1,2
Operating temperature	Тор	-40	-	85	$^{\circ}\!\mathbb{C}$	-
Storage temperature	Tst	-40	-	85	$^{\circ}$ C	3
Life time(120cd/m ²)	-	10,000	-	-	hour	4
Life time(80cd/m ²)	-	30,000	-	-	hour	4
Life time(60cd/m ²)	-	50,000	-	-	hour	4
Humidity	-	_	-	90	%RH	_

Note 1: All the above voltages are on the basis of " $V_{SS} = 0V$ ".

Note 2: When this module is used beyond the above absolute maximum ratings, permanent breakage of the module may occur. Also, for normal operations, it is desirable to use this module under the conditions according to "electro-optical characteristics". If this module is used beyond these conditions, malfunctioning of the module can occur and the reliability of the module may deteriorate.

Note 3: The defined temperature ranges do not include the polarizer. The maximum withstood temperature of the polarizer should be 80°C.

Note 4: $V_{CC} = 9.0V$, $T_a = 25$ °C, 50% Checkerboard.

Software configuration follows Actual Application Example.

End of lifetime is specified as 50% of initial brightness reached. The average operating lifetime at room temperature is estimated by the accelerated operation at high temperature conditions.



■ ELECTRICAL CHARACTERISTICS

♦DC Characteristics

Items	Symbol	Conditions	Min	Тур.	Max	Unit
Supply voltage for logic	$V_{ m DD}$		1.65	2.8	3.3	V
Supply voltage for display (Supplied externally)	V _{CC}	Note 5	8.5	9.0	9.5	V
Supply voltage for DC/DC	V _{BAT}	Internal DC/DC enable	3.5	-	4.2	V
Supply voltage for display (Generated by internal DC/DC)	V _{CC}	Note 5	7.0	-	7.5	V
High level input	$V_{ m IH}$		$0.8 \times V_{DD}$	-	V_{DD}	V
Low level input	V_{IL}		0	-	$0.2 \times V_{DD}$	V
High level output	V _{OH}	$I_{OUT} = 100 \mu\text{A}, 3.3 \text{MH}$	0.9 x V _{DD}	-	$V_{ m DD}$	V
Low level output	Vol	$I_{OUT} = 100 \mu\text{A}, 3.3 \text{MH}$	0	-	$0.1x V_{DD}$	V
Operating current for V _{DD}	I _{DD}		-	180	300	μA
Operating current for V _{CC} (V _{CC} Supplied externally)	I _{CC}	Note 6	-	9.0	15.0	mA
Operating current for V _{DDB} (V _{CC} Generated by internal DC/DC)	I _{BAT}	Note 7	-	25.0	32.0	mA
Sleep mode current for V _{DD}	I _{DD,SLEEP}		-	1	5	μA
Sleep mode current for V _{CC}	I _{CC,SLEEP}		-	2	10	μA

Note 5: Supply Voltage for Display (V_{CC}) are subject to the change of the panel characteristics and the customer's request.

Note 6: V_{DD} = 2.8V, V_{CC} = 9.0V, 100% Display Area Turn on.

Note 7: V_{DD}= 2.8V, V_{CC}= 7.25V, 100% Display Area Turn on.

^{*} Software configuration follows Actual Application Example .

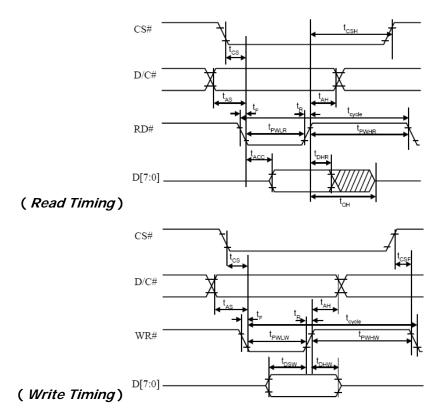


♦AC Characteristics

1. 80XX-Series MPU Parallel Interface Timing Characteristics:

Symbol	Description	Min	Max	Unit
t _{cycle}	Clock Cycle Time	300	-	ns
t _{AS}	Address Setup Time	10	-	ns
t _{AH}	Address Hold Time	0	-	ns
t_{DSW}	Write Data Setup Time	40	_	ns
t_{DHW}	Write Data Hold Time	7	-	ns
t _{DHR}	Read Data Hold Time	20	_	ns
t _{OH}	Output Disable Time	_	70	ns
t _{ACC}	Access Time	_	140	ns
t _{PWLR}	Read Low Time	120	_	ns
t _{PWLW}	Write Low Time	60	_	ns
t _{PWHR}	Read High Time	60	_	ns
t _{PWHW}	Write High Time	60	_	ns
t_{CS}	Chip Select Setup Time	0	_	ns
t _{CSH}	Chip Select Hold Time to Read Signal	0	_	ns
t _{CSF}	Chip Select Hold Time	20	_	ns
t _R	Rise Time	_	40	ns
t _F	Fall Time	_	40	ns

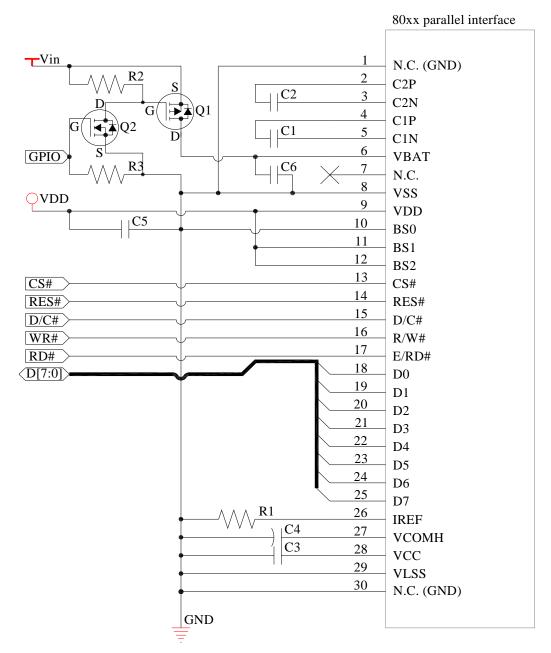
^{* (} V_{DD} - V_{SS} = 1.65V to 3.3V, T_a = 25°C)





1.1 80XX-Series MPU Parallel Interface With Interface Charge Pump

Special Tips: When design main board, Please add Electronic Switch circuit, otherwise, will be caused leak current.



Recommended Components:

C1, C2: 1µF / 16V, X5R

C3: 2.2µF

C4: 4.7µF / 16V, X7R

C5, C6: 1µF

R1: $910k\Omega$, R1 = (Voltage at IREF - VSS) / IREF

R2, R3: 47kΩ Q1: FDN338P Q2: FDN335N

Notes:

VDD: 1.65~3.3V, it should be equal to MPU I/O voltage.

Vin: 3.5~4.2V

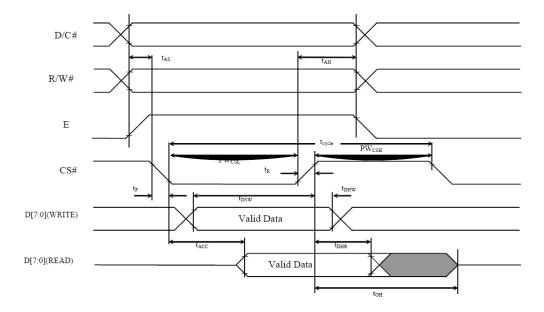
^{*} VBAT will be connected to VDD when VCC be connected to external source (12V), R1 should be replaced as **910 k\Omega**.



2. 68XX-Series MPU Parallel Interface Timing Characteristics:

Symbol	Description	Min	Max	Unit
t _{cycle}	Clock Cycle Time	300	-	ns
t _{AS}	Address Setup Time	0	-	ns
t _{AH}	Address Hold Time	0	-	ns
t _{DSW}	Write Data Setup Time	40	-	ns
t_{DHW}	Write Data Hold Time	7	-	ns
t _{DHR}	Read Data Hold Time	20	-	ns
t _{OH}	Output Disable Time	-	70	ns
t _{ACC}	Access Time	-	140	ns
DVA	Chip Select Low Pulse Width (Read)	120		20
PW _{CSL}	Chip Select Low Pulse width (Write)	60	-	ns
DIA	Chip Select High Pulse Width (Read)	60		200
PW _{CSH}	Chip Select High Pulse Width (Write)	60	-	ns
t _R	Rise Time	_	40	ns
t	Fall Time	-	40	ns

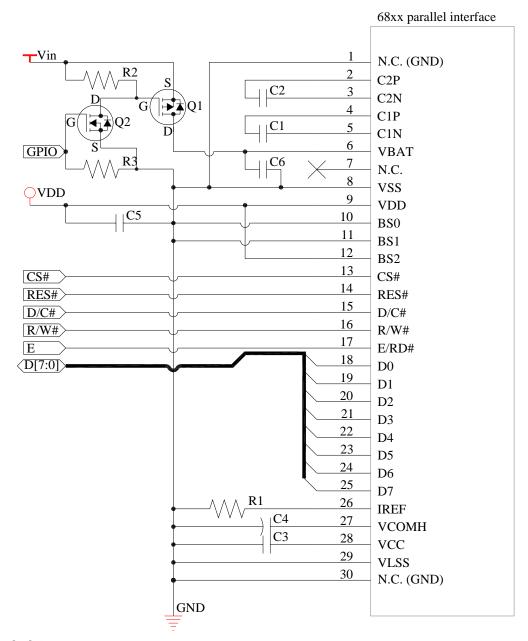
* (V_{DD} - V_{SS} = 1.65V to 3.3V, T_a = 25°C)





2.1 68XX-Series MPU Parallel Interface With Interface Charge Pump

Special Tips: When design main board, Please add Electronic Switch circuit, otherwise, will be caused leak current.



Recommended Components:

C1, C2: 1µF / 16V, X5R

C3: $2.2\mu F$

C4: 4.7µF / 16V, X7R

C5, C6: 1µF

R1: $910k\Omega$, R1 = (Voltage at IREF - VSS) / IREF

R2, R3: 47kΩ Q1: FDN338P Q2: FDN335N

Notes:

VDD: 1.65~3.3V, it should be equal to MPU I/O voltage.

Vin: 3.5~4.2V

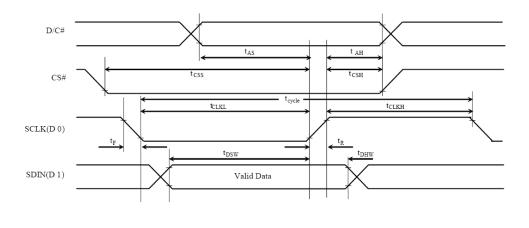
^{*} VBAT will be connected to VDD when VCC be connected to external source (12V), R1 should be replaced as $910 \ k\Omega$.

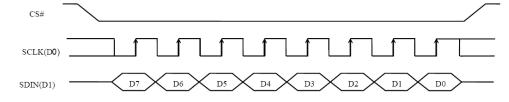


3. Serial Interface Timing Characteristics: (4-wire SPI)

Symbol	Description	Min	Max	Unit
t _{cycle}	Clock Cycle Time	100	-	ns
t _{AS}	Address Setup Time	15	-	ns
t _{AH}	Address Hold Time	15	-	ns
t_{CSS}	Chip Select Setup Time	20	-	ns
t_{CSH}	Chip Select Hold Time	10	-	ns
t_{DSW}	Write Data Setup Time	15	-	ns
t_{DHW}	Write Data Hold Time	15	-	ns
t _{CLKL}	Clock Low Time	20	-	ns
t _{CLKH}	Clock High Time	20	-	ns
t_R	Rise Time	-	40	ns
t _F	Fall Time	ı	40	ns

* (V_{DD} - V_{SS} = 1.65V to 3.3V, T_a = 25°C)

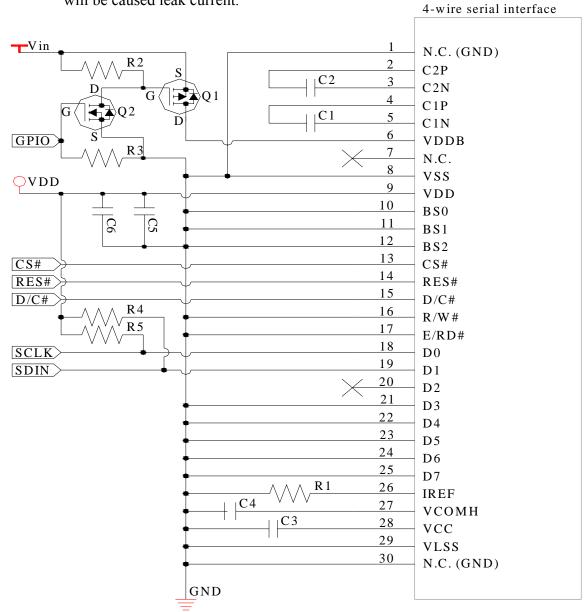






3.1 4-wire Serial Interface With Interface Charge Pump

Special Tips: When design main board, Please add Electronic Switch circuit, otherwise, will be caused leak current.



Recommended Components:

C1, C2: 1µF / 16V, X5R

C3: 2.2µF

C4: 4.7µF / 16V, X7R

C5, C6: 1µF

R1: $910k\Omega$, R1 = (Voltage at IREF - VSS) / IREF

R2, R3: 47kΩR4, R5: 4.7kΩQ1: FDN338P Q2: FDN335N

Notes:

VDD: 1.65~3.3V, it should be equal to MPU I/O voltage.

Vin: 3.5~4.2V

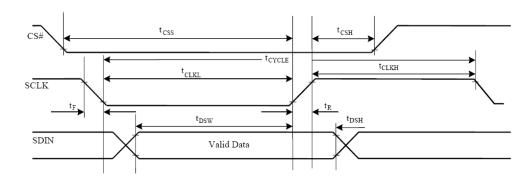
^{*} VBAT will be connected to VDD when VCC be connected to external source (12V), R1 should be replaced as **910 k\Omega**.

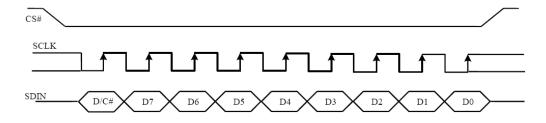


4. Serial Interface Timing Characteristics: (3-wire SPI)

Symbol	Description	Min	Max	Unit
t _{cycle}	Clock Cycle Time	100	-	ns
t_{CSS}	Chip Select Setup Time	20	-	ns
t _{CSH}	Chip Select Hold Time	10	_	ns
t _{DSW}	Write Data Setup Time	15	_	ns
t _{DHW}	Write Data Hold Time	15	_	ns
t _{CLKL}	Clock Low Time	20	_	ns
t _{CLKH}	Clock High Time	20	_	ns
t _R	Rise Time	_	40	ns
t _F	Fall Time	_	40	ns

* (V_{DD} - V_{SS} = 1.65V to 3.3V, T_a = 25°C)

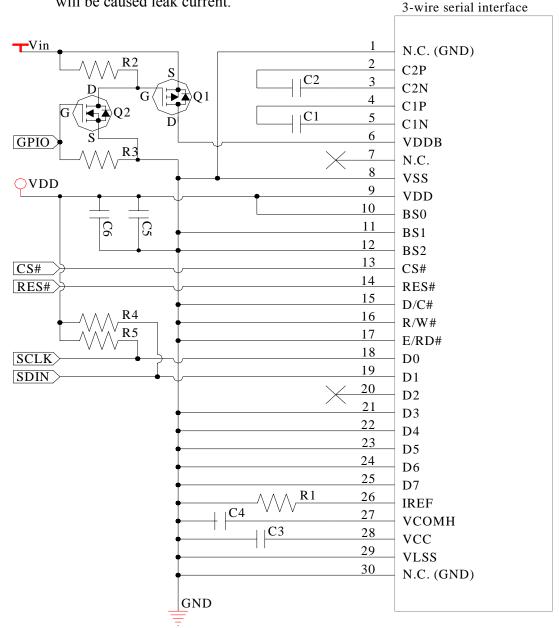






4.1 3-wire Serial Interface With Interface Charge Pump

Special Tips: When design main board, Please add Electronic Switch circuit, otherwise, will be caused leak current.



Recommended Components:

C1, C2: 1µF / 16V, X5R C3: 2.2UF/16V C4: 4.7µF / 16V, X7R

C5, C6: 1µF/16V

R1: $910k\Omega$, R1 = (Voltage at IREF - VSS) / IREF

R2, R3: 47kΩR4, R5: 4.7kΩQ1: FDN338P Q2: FDN335N

Notes:

VDD: 1.65~3.3V, it should be equal to MPU I/O voltage.

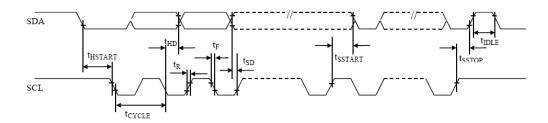
Vin: 3.5~4.2V

^{*} VBAT will be connected to VDD when VCC be connected to external source (12V), R1 should be replaced as **910** $k\Omega$.

5. I²C Interface Timing Characteristics:

Symbol	Description	Min	Max	Unit
t _{cycle}	Clock Cycle Time	2.5	-	μs
t _{HSTART}	Start Condition Hold Time	0.6	-	μs
_	Data Hold Time (for "SDA _{OUT} " Pin)	0		20
t _{HD}	Data Hold Time (for "SDA _{IN} " Pin)	300	_	ns
t _{SD}	Data Setup Time	100	_	ns
t _{SSTART}	Start Condition Setup Time (Only relevant for a repeated Start condition)	0.6	-	μs
t _{SSTOP}	Stop Condition Setup Time	0.6	-	μs
t _R	Rise Time for Data and Clock Pin		300	ns
t _F	Fall Time for Data and Clock Pin		300	ns
t _{IDLE}	Idle Time before a New Transmission can Start	1.3	_	μs

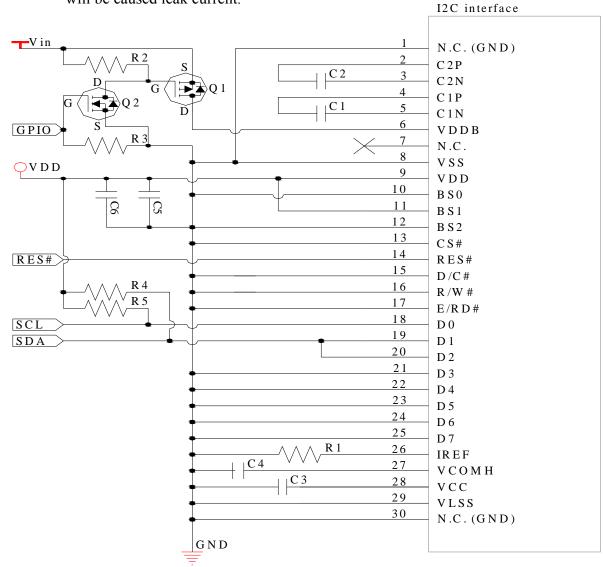
^{* (} V_{DD} - V_{SS} = 1.65V to 3.3V, T_a = 25°C)





5.1 I²C Interface With Interface Charge Pump

Special Tips: When design main board, Please add Electronic Switch circuit, otherwise, will be caused leak current.



Recommended Components:

C1, C2: 1µF / 16V, X5R

C3: 2.2µF

C4: 4.7µF / 16V, X7R

C5, C6: 1µF

R1: $910k\Omega$, R1 = (Voltage at IREF - VSS) / IREF

R2, R3: 47kΩR4, R5: 4.7kΩQ1: FDN338P Q2: FDN335N

Notes:

VDD: 1.65~3.3V, it should be equal to MPU I/O voltage.

Vin: 3.5~4.2V

The I^2C slave address is 0111100b'. If the customer ties D/C# (pin 15) to VDD, the I^2C slave address will be 0111101b'.

^{*} VBAT will be connected to VDD when VCC be connected to external source (12V), R1 should be replaced as $\bf 910~k\Omega$.



■ TIMING OF POWER SUPPLY

1. Commands

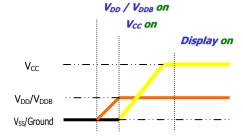
Refer to the Technical Manual for the SSD1306

2. Power down and Power up Sequence

To protect OEL panel and extend the panel life time, the driver IC power up/down routine should include a delay period between high voltage and low voltage power sources during turn on/off. It gives the OEL panel enough time to complete the action of charge and discharge before/after the operation.

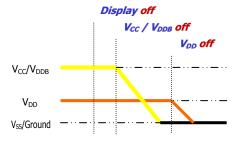
2.1 Power up Sequence:

- 1. Power up V_{DD} / V_{DDB}
- 2. Send Display off command
- 3. Initialization
- 4. Clear Screen
- 5. Power up V_{CC}
- 6. Delay 100ms (When V_{CC} is stable)
- 7. Send Display on command



2.2 Power down Sequence:

- 1. Send Display off command
- 2. Power down V_{CC} / V_{DDB}
- 3. Delay 100ms (When V_{CC} / V_{DDB} is reach 0 and panel is completely discharges)
- 4. Power down V_{DD}



Note 8:

- 1) Since an ESD protection circuit is connected between V_{DD} and V_{CC} inside the driver IC, V_{CC} becomes lower than V_{DD} whenever V_{DD} is ON and V_{CC} is OFF.
- 2) V_{CC} / V_{DDB} should be kept float (disable) when it is OFF.
- 3) Power Pins (V_{DD} , V_{CC} , V_{DDB}) can never be pulled to ground under any circumstance.
- 4) V_{DD} should not be power down before V_{CC} / V_{DDB} power down.

3. Reset Circuit

When RES# input is low, the chip is initialized with the following status:

- 1. Display is OFF
- 2. 128×64 Display Mode
- 3. Normal segment and display data column and row address mapping (SEG0 mapped to column address 00h and COM0 mapped to row address 00h)
- 4. Shift register data clear in serial interface
- 5. Display start line is set at display RAM address 0
- 6. Column address counter is set at 0
- 7. Normal scan direction of the COM outputs
- 8. Contrast control register is set at 7Fh
- 9. Normal display mode (Equivalent to A4h command)

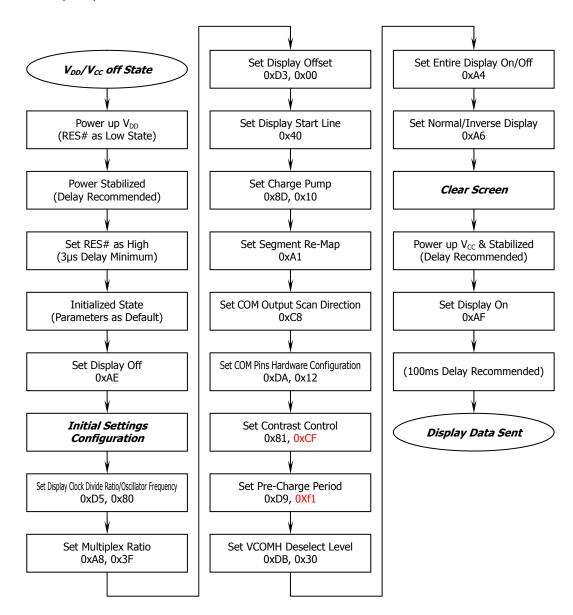


4. Actual Application Example

Command usage and explanation of an actual example

4.1 V cc Supplied Externally

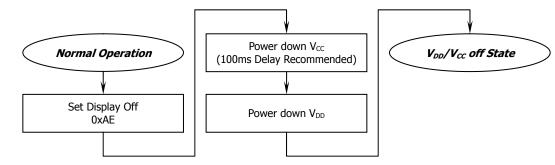
<Power up Sequence>



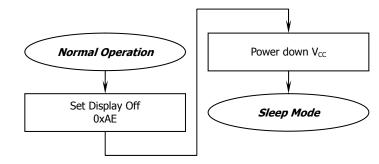
If the noise is accidentally occurred at the displaying window during the operation, please reset the display in order to recover the display function.



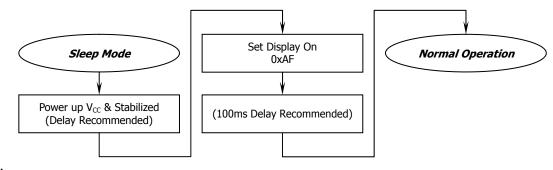
<Power down Sequence>



<Entering Sleep Mode>



<Exiting Sleep Mode>



External setting

```
RES=1;
   delay(1000);
   RES=0;
   delay(1000);
   RES=1;
   delay(1000);
write_i(0xAE);
                  /*display off*/
write_i(0x00);
                  /*set lower column address*/
write_i(0x10);
                  /*set higher column address*/
write_i(0x40);
                  /*set display start line*/
write_i(0xB0);
                  /*set page address*/
```



```
write_i(0x81);
                          /*contract control*/
       write_i(0xCF);
                          /*128*/
       write_i(0xA1);
                          /*set segment remap*/
       write_i(0xA6);
                          /*normal / reverse*/
       write_i(0xA8);
                          /*multiplex ratio*/
       write_i(0x3F);
                          /*duty = 1/64*/
       write_i(0xC8);
                          /*Com scan direction*/
       write_i(0xD3);
                          /*set display offset*/
       write_i(0x00);
       write_i(0xD5);
                          /*set osc division*/
       write_i(0x80);
       write_i(0xD9);
                          /*set pre-charge period*/
       write_i(0Xf1);
                          /*set COM pins*/
       write_i(0xDA);
       write_i(0x12);
       write_i(0xdb);
                          /*set vcomh*/
       write_i(0x30);
       write_i(0x8d);
                          /*set charge pump disable*/
       write_i(0x10);
       write_i(0xAF);
                          /*display ON*/
void write_i(unsigned char ins)
   DC=0;
   CS=0;
   WR=1;
                  /*inst*/
   P1=ins;
   WR=0;
   WR=1;
   CS=1;
}
void write_d(unsigned char dat)
   DC=1;
```

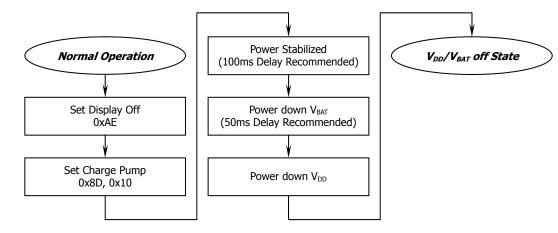


```
CS=0;
    WR=1;
    P1=dat;
                          /*data*/
    WR=0;
    WR=1;
    CS=1;
}
void delay(unsigned int i)
      while(i>0)
  4.2 V CC Generated by Internal DC/DC Circuit
        <Power up Sequence>
                                                 Set Multiplex Ratio
                                                                                   Set Entire Display On/Off
            V<sub>DD</sub>/V<sub>BAT</sub> off State
                                                     0xA8, 0x3F
                                                                                             0xA4
              Power up V<sub>DD</sub>
                                                 Set Display Offset
                                                                                  Set Normal/Inverse Display
           (RES# as Low State)
                                                    0xD3, 0x00
                                                                                             0xA6
             Power Stabilized
                                                Set Display Start Line
                                                                                         Clear Screen
          (Delay Recommended)
                                                                                       Set Charge Pump
              Power up V_{\text{DDB}}
                                                Set Segment Re-Map
       (100ms Delay Recommended)
                                                       0xA1
                                                                                          0x8D, 0x14
            Set RES# as High
                                           Set COM Output Scan Direction
                                                                                        Set Display On
           (3µs Delay Minimum)
                                                       0xC8
                                                                                             0xAF
             Initialized State
                                           Set COM Pins Hardware Configuration
                                                                                       Power Stabilized
         (Parameters as Default)
                                                    0xDA, 0x12
                                                                                 (100ms Delay Recommended)
             Set Display Off
                                                Set Contrast Control
                                                                                     Display Data Sent
                  0xAE
                                                     0x81, 0xCF
             Initial Settings
                                                Set Pre-Charge Period
             Configuration
                                                     0xD9, 0xF1
      Set Display Clock Divide Ratio/Oscillator Frequency
                                             Set VCOMH Deselect Level
               0xD5, 0x80
                                                    0xDB, 0x30
```

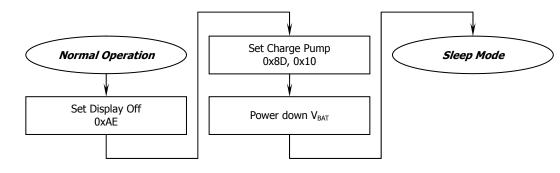
If the noise is accidentally occurred at the displaying window during the operation, please reset the display in order to recover the display function.



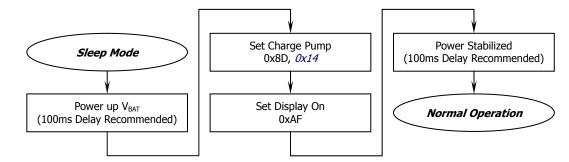
<Power down Sequence>



<Entering Sleep Mode>



<Exiting Sleep Mode>



```
Internal setting (Charge pump)

{

RES=1;
delay(1000);
RES=0;
delay(1000);
RES=1;
delay(1000);
write_i(0xAE); /*display off*/

write_i(0x00); /*set lower column address*/
write_i(0x10); /*set higher column address*/
```



```
write_i(0x40);
                          /*set display start line*/
       write_i(0xB0);
                          /*set page address*/
       write_i(0x81);
                          /*contract control*/
       write_i(0xCF);
                          /*128*/
       write_i(0xA1);
                          /*set segment remap*/
       write_i(0xA6);
                          /*normal / reverse*/
       write_i(0xA8);
                          /*multiplex ratio*/
                          /*duty = 1/64*/
       write_i(0x3F);
       write_i(0xC8);
                          /*Com scan direction*/
                          /*set display offset*/
       write_i(0xD3);
       write_i(0x00);
       write_i(0xD5);
                          /*set osc division*/
       write_i(0x80);
       write_i(0xD9);
                          /*set pre-charge period*/
       write_i(0Xf1);
       write_i(0xDA);
                          /*set COM pins*/
       write_i(0x12);
       write_i(0xdb);
                          /*set vcomh*/
       write_i(0x30);
       write_i(0x8d);
                          /*set charge pump enable*/
       write_i(0x14);
                          /*display ON*/
       write_i(0xAF);
       }
void write_i(unsigned char ins)
   DC=0;
   CS=0;
   WR=1;
   P1=ins;
                  /*inst*/
   WR=0;
   WR=1;
   CS=1;
```





MODULE NO.: MI12864LO-W Ver 1.2

■ ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

Items		Symbol	Min.	Тур.	Max.	Unit	Remark
Brightness(Vcc supplied externally)		Lbr	120	-	-	cd /m ²	White
Brightness(Vcc generated by internal DC/DC)		Lbr	80	120	-	cd /m ²	White
Color Coordinate	White	CIE x	0.25	0.29	0.33	-	Without Polarizer
		CIE y	0.27	0.31	0.35		
Contrast Ratio*		Cr	-	20000:1	1		Darkroom
Viewing Angle Uniformity		Δ θ	-	Free	-	Degree	-

Note: Brightness (L_{br}) is subject to the change of the panel characteristics and the customer's request.

^{*} Optical measurement taken at $V_{DD} = 2.8V$, $V_{CC} = 9V\&7.25V$.

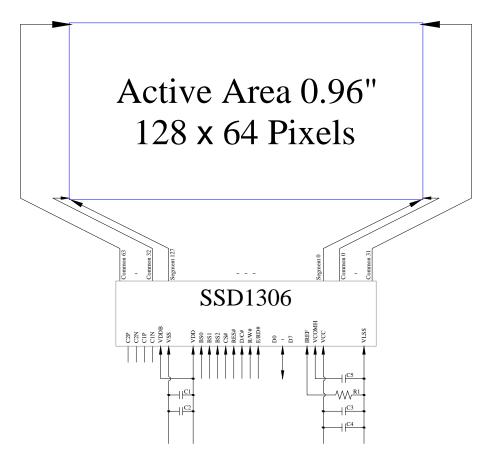


MODULE NO.: MI12864LO-W Ver 1.2

■ INTERFACE PIN CONNECTIONS

1. Block Diagram

1.1 V_{CC} Supplied Externally



MCU Interface Selection: BS0, BS1 and BS2

Pins connected to MCU interface: CS#, RES#, D/C#, R/W#, E/RD#, and D0~D7

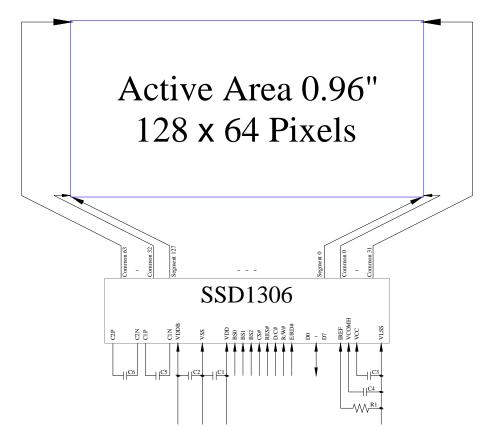
C1, C3: 0.1µF C2: 4.7µF

C4, C5: 4.7µF / 16V X7R

910k Ω , R1 = (Voltage at IREF - VSS) / IREF



1.2 V CC Generated by Internal DC/DC Circuit



MCU Interface Selection: BS0, BS1 and BS2

Pins connected to MCU interface: CS#, RES#, D/C#, R/W#, E/RD#, and D0~D7

C1, C2: 1µF C3: 2.2µF

C4: 4.7µF / 16V X7R C5, C6: 1µF / 16V X5R

R1: $910k\Omega$, R1 = (Voltage at IREF - VSS) / IREF



2. Pin Definition

Pin Number	Symbol	I/O	Function		
Power Suppl	у	•			
9	VDD	Р	Power Supply for Logic This is a voltage supply pin. It must be connected to external source.		
8	VSS	Р	Ground of Logic Circuit This is a ground pin. It acts as a reference for the logic pins. It must be connected to external ground.		
28	VCC	Р	Power Supply for OEL Panel This is the most positive voltage supply pin of the chip. A stabilization capacitor should be connected between this pin and V_{SS} when the converter is used. It must be connected to external source when the converter is not used.		
29	VLSS	Р	Ground of Analog Circuit This is an analog ground pin. It should be connected to V _{SS} externally.		
Driver					
26	IREF	I	Current Reference for Brightness Adjustment This pin is segment current reference pin. A resistor should be connected between this pin and V_{SS} . Set the current at $12.5\mu A$ maximum.		
27	VCOMH	0	Voltage Output High Level for COM Signal This pin is the input pin for the voltage output high level for COM signals. A capacitor should be connected between this pin and V_{SS} .		
DC/DC Conve	erter				
6	VDDB	Р	Power Supply for DC/DC Converter Circuit This is the power supply pin for the internal buffer of the DC/DC voltage converter. It must be connected to external source when the converter is used. It should be connected to V _{DD} when the converter is not used.		
4 / 5 2 / 3	C1P / C1N C2P / C2N	I	Positive Terminal of the Flying Inverting Capacitor Negative Terminal of the Flying Boost Capacitor The charge-pump capacitors are required between the terminals. They must be floated when the converter is not used.		
Interface					
10 11 12	BS0 BS1 BS2	I	Communicating Protocol Select These pins are MCU interface selection input. See the following table: BS0 BS1 BS2 I²C 0 1 0 3-wire SPI 1 0 0 4-wire SPI 0 0 0 8-bit 68XX Parallel 0 0 1 8-bit 80XX Parallel 0 1 1		
14	RES#	I	Power Reset for Controller and Driver This pin is reset signal input. When the pin is low, initialization of the chip is executed. Keep this pin pull high during pormal operation.		
13	CS#	I	 executed. Keep this pin pull high during normal operation. Chip Select This pin is the chip select input. The chip is enabled for MCU communication only when CS# is pulled low. 		
15	D/C#	I	Data/Command Control This pin is Data/Command control pin. When the pin is pulled high, the input at D7~D0 is treated as display data. When the pin is pulled low, the input at D7~D0 will be transferred to the command register. When the pin is pulled high and serial interface mode is selected, the data at SDIN will be interpreted as data. When it is pulled low, the data at SDIN will be transferred to the command register. In I²C mode, this pin acts as SA0 for slave address selection. For detail relationship to MCU interface signals, please refer to the Timing Characteristics Diagrams.		
17	E/RD#	I	Read/Write Enable or Read This pin is MCU interface input. When interfacing to a 68XX-series microprocessor, this pin will be used as the Enable (E) signal. Read/write operation is initiated when this pin is pulled high and the CS# is pulled low. When connecting to an 80XX-microprocessor, this pin receives the Read (RD#) signal. Data read operation is initiated when this pin is pulled low and CS# is pulled low. When serial or I²C mode is selected, this pin must be connected to V _{SS} .		



Pin Number	Symbol	I/O	Function		
Interface(Co	Interface(Continued)				
16	R/W#	I	Read/Write Select or Write This pin is MCU interface input. When interfacing to a 68XX-series microprocessor, this pin will be used as Read/Write (R/W#) selection input. Pull this pin to "High" for read mode and pull it to "Low" for write mode. When 80XX interface mode is selected, this pin will be the Write (WR#) input. Data write operation is initiated when this pin is pulled low and the CS# is pulled low. When serial or I²C mode is selected, this pin must be connected to Vss.		
18~25	D0~D7	I/O	Host Data Input/Output Bus These pins are 8-bit bi-directional data bus to be connected to the microprocessor's data bus. When serial mode is selected, D1 will be the serial data input SDIN and D0 will be the serial clock input SCLK. When I²C mode is selected, D2 & D1 should be tired together and serve as SDA _{out} & SDA _{in} in application and D0 is the serial clock input SCL. Unused pins must be connected to V _{SS} except for D2 in serial mode.		
Reserve	Reserve				
7	N.C.	-	Reserved Pin The N.C. pin between function pins are reserved for compatible and flexible design.		
1, 30	N.C. (GND)	_	Reserved Pin (Supporting Pin) The supporting pins can reduce the influences from stresses on the function pins. These pins must be connected to external ground as the ESD protection circuit.		



MODULE NO.: MI12864LO-W Ver 1.2

■ RELIABILITY TESTS

Item		Condition	Criterion	
High Temperature Storage (HTS)		85±2°C, 240 hours	 After testing, the function test is ok. After testing, no addition to the defect. 	
High Temperature Operating (HTO)		85±2°C, 240 hours	3. After testing, the change of luminance should be within +/- 50% of initial value.	
Low Temperature Storage (LTS)		-40±2°C, 240 hours	4. After testing, the change for the mono and area color must be within (+/-0.02, +/-	
Low Temperature Operating (LTO)		-30±2°C, 240 hours	0.02) and for the full color it must be within (+/-0.04, +/-0.04) of	
High Temperature / High Humidity Storage (HTHHS)		60±3°C, 90%±3%RH, 120 hours	initial value based on 1931 CIE coordinates. 5. After testing, the change of total current consumption should be	
Thermal Shock		-40±2°C ~ 25°C ~ 85±2°C (30min) (5min) (30min) 24cycles	within +/- 50% of initial value.	
Vibration (Packing)	10~55~10Hz,amplitu de 1.5mm, 1 hour for each direction x, y, z	1. One box for each test.	e and the electrical defects.	
Drop (Packing)	Height: 1 m, each time for 6 sides, 3 edges, 1 angle	2. No addition to the cosmetic		

Note: 1) For each reliability test, the sample quantity is 3, and only for one test item.

2) The HTHHS test is requested the Pure Water(Resistance> $10M\Omega$).



MODULE NO.: MI12864LO-W Ver 1.2

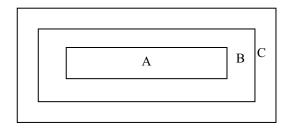
■OUTGOING QUALITY CONTROL SPECIFICATION

♦Standard

According to GB/T2828.1-2003/ISO 2859-1: 1999 and ANSI/ASQC Z1.4-1993, General Inspection Level II.

♦ Definition

- 1 Major defect: The defect that greatly affect the usability of product.
- 2 Minor defect: The other defects, such as cosmetic defects, etc.
- 3 Definition of inspection zone:



Zone A: Active Area

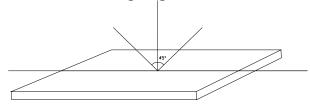
Zone B: Viewing Area except Zone A

Zone C: Outside Viewing Area

Note: As a general rule, visual defects in Zone C are permissible, when it is no trouble of quality and assembly to customer's product.

◆Inspection Methods

1 The general inspection: under 20W x 2 or 40W fluorescent light, about 30cm viewing distance, within 45° viewing angle, under 25±5°C.



2 The luminance and color coordinate inspection: By PR705 or BM-7 or the equal equipments, in the dark room, under 25 ± 5 °C.

♦Inspection Criteria

1 Major defect : AQL= 0.65

J			
Item	Criterion		
	1. No display or abnormal display is not accepted		
Function Defect	2. Open or short is not accepted.		
	3. Power consumption exceeding the spec is not accepted.		
Outline Dimension	Outline dimension exceeding the spec is not accepted.		
Glass Crack	Glass crack tends to enlarge is not accepted.		

2 Minor Defect : AQL= 1.5



Item	Criterion					
	Size	(mm)	Accepted Qty			
Spot Defect (dimming and lighting			Area A + Area B	Area C		
		Φ≦0.10	Ignored			
	Y	0.10<Φ≦0.15	3	Ignored		
		$0.15 < \Phi \le 0.20$	1			
spot)	 - 	0.20<₽	0			
	Note: $\Phi = (x + y) /$	2				
Line	L (Length): mm	W (Width): mm	Area A + Area B	Area C		
Defect	/	W ≦ 0.03	Ignored			
(dimming and	L≦3.0	$0.03 < W \le 0.05$	2			
lighting	L≦2.0	$0.05 < W \le 0.08$	1	Ignored		
line)	/	0.08 <w< td=""><td>As spot defect</td><td></td></w<>	As spot defect			
Remarks: Tl	Remarks: The total of spot defect and line defect shall not exceed 4 pcs.					
Polarizer	Stain which can be wiped off lightly with a soft cloth or similar			ar		
Stain	cleaning is accepted, otherwise, according to the Spot Defect and the Line Defect.					
	1. If scratch can be seen during operation, according to the crite					
	of the Spot Defect and the Line Defect. 2. If scratch can be seen only under non-operation or some special					
	angle, the criterion is as below:					
Polarizer	L (Length): mm	W (Width): mm	Area A + Area B	Area C		
Scratch	/	W ≦ 0.03	Ignore			
	5.0 <l≦10.0< td=""><td>$0.03 < W \le 0.05$</td><td>2</td><td></td></l≦10.0<>	$0.03 < W \le 0.05$	2			
	L≦5.0	$0.05 < W \le 0.08$	1	Ignore		
	/	0.08 <w< td=""><td>0</td><td></td></w<>	0			
	Si	ze	Area A + Area B	Area C		
		Φ≦0.20	Ignored			
Polarizer Air Bubble	Y	$0.20 < \Phi \leq 0.50$	2			
All Duoole	X	$0.50 < \Phi \le 0.80$	1	Ignored		
		0.80<Ф	0			



	1. On the corner	(mm)				
		$X \leq 2.0$				
		y \leq S				
		$z \leq t$				
	z					
Glass Defect	2. On the bonding edge					
(Glass		(mm)				
Chiped)	Y 12	$X \leq a/2$				
		y ≤ s / 3				
		z ≤t				
	STATE OF THE PARTY					
	3. On the other edges					
		(mm)				
	The state of the s	$x \leq a/5$				
		y ≤ 1.0				
		$z \leq t$				
	Note: t: glass thickness; s: pad width; a: the	length of the edge				
TCP Defect	Crack, deep fold and deep pressure mark on the TCP are not accepted					
Pixel Size	The tolerance of display pixel dimension should be within $\pm 20\%$ of the spec					
Luminance	Refer to the spec or the reference sample					
Color	Refer to the spec or the reference sample					

■ CAUTIONS IN USING OLED MODULE

◆Precautions For Handling OLED Module:

- 1. OLED module consists of glass and polarizer. Pay attention to the following items when handling:
 - i. Avoid drop from high, avoid excessive impact and pressure.
 - ii. Do not touch, push or rub the exposed polarizers with anything harder than an HB pencil lead.
 - iii. If the surface becomes dirty, breathe on the surface and gently wipe it off with a soft dry cloth. If it is terrible dirty, moisten the soft cloth with Isopropyl alcohol or Ethyl alcohol. Other solvents may damage the polarizer. Especially water, Ketone and Aromatic solvents.
 - iv. Wipe off saliva or water drops immediately, contact the polarizer with water over a long period of time may cause deformation.
 - v. Please keep the temperature within specified range for use and storage. Polarization degradation, bubble generation or polarizer peeling-off may occur with high temperature and high humidity.
 - vi. Condensation on the surface and the terminals due to cold or anything will damage, stain or dirty the polarizer, so make it clean as the way of iii.
- 2. Do not attempt to disassemble or process the OLED Module.
- 3. Make sure the TCP or the FPC of the Module is free of twisting, warping and distortion, do not pull or bend them forcefully, especially the soldering pins. On the other side, the SLIT part of the TCP is made to bend in the necessary case.
- 4. When assembling the module into other equipment, give the glass enough space to avoid excessive pressure on the glass, especially the glass cover which is much more fragile.
- 5. Be sure to keep the air pressure under 120 kPa, otherwise the glass cover is to be cracked.
- 6. Be careful to prevent damage by static electricity:
 - i. Be sure to ground the body when handling the OLED Modules.
 - ii. All machines and tools required for assembling, such as soldering irons, must be properly grounded.
 - iii. Do not assemble and do no other work under dry conditions to reduce the amount of static electricity generated. A relative humidity of 50%-60% is recommended.
 - iv. Peel off the protective film slowly to avoid the amount of static electricity generated.
 - v. Avoid to touch the circuit, the soldering pins and the IC on the Module by the body.
 - vi. Be sure to use anti-static package.
- 7. Contamination on terminals can cause an electrochemical reaction and corrade the terminal circuit, so make it clean anytime.
- 8. All terminals should be open, do not attach any conductor or semiconductor on the terminals.
- 9. When the logic circuit power is off, do not apply the input signals.
- 10. Power on sequence: $V_{DD} \rightarrow V_{PP}$, and power off sequence: $V_{PP} \rightarrow V_{DD}$.
- 11. Be sure to keep temperature, humidity and voltage within the ranges of the spec, otherwise shorten Module's life time, even make it damaged.
- 12. Be sure to drive the OLED Module following the Specification and Datasheet of IC controller, otherwise something wrong may be seen.

13. When displaying images, keep them rolling, and avoid one fixed image displaying more than 30 seconds, otherwise the residue image is to be seen. This is the speciality of OLED.

◆Precautions For Soldering OLED Module:

- 1. Soldering temperature : $260^{\circ}\text{C} \pm 10^{\circ}\text{C}$.
- 2. Soldering time: 3-4 sec.
- 3. Repeating time: no more than 3 times.
- 4. If soldering flux is used, be sure to remove any remaining flux after finishing soldering operation. (This does not apply in the case of a non-halogen type of flux.) It is recommended to protect the surface with a cover during soldering to prevent any damage due to flux spatters.

♦ Precautions For Storing OLED Module:

- 1. Be sure to store the OLED Module in the vacuum bag with dessicant.
- 2. If the Module can not be used up in 1 month after the bag being opened, make sure to seal the Module in the vacuum bag with dessicant again.
- 3. Store the Module in a dark place, do not expose to sunlight or fluorescent light.
- 4. The polarizer surface should not touch any other objects. It is recommended to store the Module in the shipping container.
- 5. It is recommended to keep the temperature between 0° C and 30° C, the relative humidity not over 60° M.

♦ Limited Warranty

Unless relevant quality agreements signed with customer and law enforcement, for a period of 12 months from date of production, all products (except automotive products) Multi-Inno will replace or repair any of its OLED modules which are found to be functional defect when inspected in accordance with Multi-Inno OLED acceptance standards (copies available upon request). Cosmetic/visual defects must be returned to Multi-Inno within 90 days of shipment. Confirmation of such date should be based on freight documents. The warranty liability of Multi-Inno is limited to repair and/or replacement on the terms above. Multi-Inno will not be responsible for any subsequent or consequential events.

◆Return OLED Module Under Warranty:

- 1. No warranty in the case that the precautions are disregarded.
- 2. Module repairs will be invoiced to the customer upon mutual agreement. Modules must be returned with sufficient description of the failures or defects.